

Product Bulletin

Document #: PB21353Z Issue Date: 1 June 2016

Title of Change:	NCV97310 and NCV97311 external components required for Low-Iq Mode.
Effective date:	1 June 2016
Contact information:	Contact your local ON Semiconductor Sales Office or voill.fontes@onsemi.com>
Type of notification:	ON Semiconductor will consider this change accepted.
Change category:	☐ Wafer Fab Change ☐ Assembly Change ☐ Test Change ☐ Other: <u>Datasheet Change</u>
Change Sub-Category(s): □ Datasheet/Product Doc change □ Manufacturing Site Change/Addition □ Material Change □ Shipping/Packaging/Marking □ Manufacturing Process Change □ Other:	
Sites Affected: ☐ All site(s) ☐ not applicable ☐ ON Semiconductor site(s): ☐ External Foundry/Subcon site(s)	
 Description and Purpose: When using Low-Iq mode, a pull-down resistor (e.g. 100 kΩ) on VDRV1 is required to meet the Iq Standby specification. a. A pull-down resistor between 10 kΩ and 1 MΩ is required from VDRV1 to GND on the PCB to keep the Iq < 35 uA while in Standby (low-Iq) mode. b. In document NCV97310/D (Rev 6), please see page 4 (Fig 3), page 5 (Fig 4), page 7, and page 20 (Low Iq Mode). c. In document NCV97311/D (Rev 4), please see page 4 (Fig 3), page 5 (Fig 4), page 7, and page 20 (Low Iq Mode). When using Low-Iq mode, a pull-up resistor is required on RSTB1 to meet the Iq Standby specification. a. Without a pull-up resistor on RSTB1, it's possible to observe an additional 50 uA of Iq while in standby (low-Iq) mode. b. In document NCV97310/D (Rev 6), please see page 4 (Fig 3), page 5 (Fig 4), page 7, page 18 (Reset), and page 20 (Low Iq Mode). c. In document NCV97311/D (Rev 4), please see page 4 (Fig 3), page 5 (Fig 4), page 7, page 18 (Reset), and page 20 (Low Iq Mode). 	
List of affected Standard Parts: NCV97310MW33R2G NCV97310MW50R2G NCV97311MW33R2G NCV97311MW50R2G	

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